# Dr. Arran Curran

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Education	Ph.D. Physics, Heriot-Watt University, Edinburgh, UK Exciton-Photon Hybridisation in ZnSe Based Microcavities Supervisors: Prof. R J Warburton and Dr A K Kar		May 2008
	MPhys in Physics, Heriot-Watt University, Edinburgh, UK Upper Second Class		Jun 2003
Research	Postdoctoral Research Associate Nano-Optics (Warburton) Group Heriot-Watt University, Edinburgh, UK		May 2008 - present
	Student Research Assistant Heriot-Watt University, Edinburgh, UK Area of Research: Experimental investigation of a single sonoluminescing bubble.		Jun - Oct 2003
	MPhys in Physics Undergraduate Project Heriot-Watt University, Edinburgh, UK Area of Research: Single bubble sonoluminescence. Awarded J. H. Murray Best Optics Project Award.		Oct 2002 - Mar 2003

## Awards & Highlights

- 2007 First demonstartion of cavity polariton bootleneck in the ZnSe material system.
- 2007 Semicond. Sci. Technol. 22, 1189 (2007) highlighted by the Institute of Physics for novelty, significance and potential impact on future research.
- 2005 Cover story in III-Vs Review. The Advanced Semicondictor Magazine. 18 30 (2005).
- 2003 First observation of single bubble sonoluminescence driven at 67 kHz.
- 2003 Awarded best Mphys project in optics at Heriot-Watt University (J. H. Murray Award).

## **Current Research**

Current research activities focus on light matter interactions on a nanometer scale. With expertise in single quantum dot laser spectroscopy, combined with a novel tunable microcavity, the interaction of photonic modes with excitonic transition in III-V and II-VI quantum strucures are explored and manipulated.

#### **Relevant Experience**

Design and fabrication of a variety semiconductor microcavities. Optical spectroscopy techniques, ensemble and micro- photoluminescence. Computational simulations of quantum and classic systems.

#### Additional Academic Experience

Tutoring in nanophysics, optoelectronics and semiconductor physics. Laboratory and tutorial demonstrator for MSc in Optoelectronic and MSc in Nanophysics. Training of 1<sup>st</sup> year Ph.D. students.

# Journal articles

R T Moug, C Bradford, A Curran, F Izdebski, I Davidson, K A Prior and R J Warburton. Development of an epitaxial lift-off technology for II-VI nanostructures using ZnMgSSe alloys. Microelectronics Journal. *in press* 

R T Moug, C Bradford, D Thuau, A Curran, R J Warburton and K A Prior. MBE Growth and characterization of MgS-rich zincblende Zn<sub>x</sub>Mg<sub>1-x</sub>S<sub>1-v</sub>Se<sub>v</sub> alloys. J. Korean Phys. Soc. *in press* 

C Bradford, R T Moug, A Curran, D Thuau, R J Warburton and K A Prior. Growth and characterization of ZnMgS grown by MBE on GaAs(100). J. Korean Phys. Soc. *in press* 

R T Moug, C Bradford, F Izdebski, I Davidson, A Curran, R J Warburton, K A Prior, A Aouni, F M Morales, S I Molina. A comparison of ZnMgSSe and MgS wide bandgap semiconductors used as barriers: growth, structure and luminescence properties. J. Crystal Growth. *in press* 

A Curran, R J Barbour, J K Morrod, K A Prior, A K Kar and R J Warburton. ZnSe Hybrid Microcavities Fabricated Using a MgS Release Layer: Strong & Weak Exciton-photon Coupling. J. Korean Phys. Soc. 53, tba (2008).

A Curran, J K Morrod, K A Prior, A K Kar and R J Warburton. Exciton-photon coupling in a ZnSe based microcavity fabricated using epitaxial liftoff. Semicond. Sci. Technol. (*IOP Select*). **22**, 1189 (2007).

T C M Graham, A Curran, X Tang, J K Morrod, K A Prior and R J Warburton. Direct and exchange Coulomb energies in CdSe/ZnSe quantum dots. Phys. Stat. Sol. B. **243**, 782 (2006).

C Bradford, A Curran, A Balocchi, B C Cavenett, K A Prior and R J Warburton. Epitaxial lift-off of MBE grown II-VI heterostructures using a novel MgS release layer. J. Crystal Growth. **278**, 325 (2005).

A Balocchi, A Curran, T C M Graham, C Bradford, K A Prior and R J Warburton. Epitaxial lift-off of ZnSebased heterostructures using a II-VI release layer. Appl. Phys. Lett. **86**, 011916 (2005).

R Szweda. Cover article featuring the works of A Curran *et. al.* ELO MBE of II-VIs at Heriot-Watt. III-Vs Review. The Advanced Semicondictor Magazine. **18**, 30 (2005).

#### Confereneces

Talk: A Curran, R J Barbour, C Bradford, J K Morrod, R Moug, K A Prior and R J Warburton. Light-matter hybridisation in wide-bandgap ZnSe-based microcavities. UK Semiconductor 2008, Sheffield, U.K. (Jul 2008)

Poster: A Curran, R J Barbour, J K Morrod, K A Prior, A K Kar and R J Warburton. ZnSe hybrid microcavities fabricated using a MgS release layer: Strong and weak exciton-photon coupling. 13<sup>th</sup> International Conference on II-VI Compounds, Jeju, South Korea (Sept 2007).

Talk: A Curran, J K Morrod, K A Prior, A K Kar and R J Warburton. ZnSe-based microcavity fabricated using epitaxial liftoff. 7<sup>th</sup> Pacific Rim Conference on Lasers and Electro-Optics (CLEO PS), Seoul, South Korea (Aug 2007).

Talk: A Curran, J K Morrod, R J Barbour, I Weidle, R Moug, C Bradford, K A Prior, A K Kar and R J Warburton. Angle resolved transmission spectroscopy of ZnSe-based microcavities fabricated using epitaxial liftoff technique. Conference on Lasers and Electro-Optics (CLEO), Baltimore, Maryland U.S.A. (May 2007).

Poster: C Bradford, A Curran, A Balocchi, B C Cavenett, K A Prior and R J Warburton. Epitaxial lift-off of MBE grown II-VI heterostructures using a novel MgS release layer. 11<sup>th</sup> International Conference on II-VI Compounds, Edinburgh, U.K. (2004).

#### Referees

Professor Richard J Warburton *Thesis Advisor* Nano-Optics Group David Brewster Building School of Engineering and Physical Science Heriot-Watt University, Edinburgh, EH14 4AS +44 (0)131 451 8069, r.j.warburton@hw.ac.uk Professor Jeremy J Baumberg *Thesis Examinor* NanoPhotonics Group Cavendish Laboratory JJ Thomson Avenue Cambridge, CB3 0HE +44 (0)122 333 7441, jjb12@cam.ac.uk